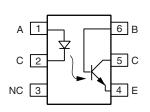
# Vishay Semiconductors



# Optocoupler, Phototransistor Output, Low Input Current, Low Input Current, with Base Connection





# • Guaranteed a

- Guaranteed at I<sub>F</sub> = 1.0 mA
- High collector emitter voltage, BV<sub>CEO</sub> = 70 V
- · Long term stability
- · Industry standard DIP package
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC





### **DESCRIPTION**

The IL201/IL202/IL203 are optically coupled pairs employing a gallium arsenide infrared LED and a silicon NPN phototransistor. Signal information, including a DC level, can be transmitted by the device while maintaining a high degree of electrical isolation between input and output. The IL201/IL202/IL203 can be used to replace relays and transformers in many digital interface applications, as well as analog applications such as CRT modulation.

#### **AGENCY APPROVALS**

- UL1577, file no. E52744 system code H or J, double protection
- DIN EN 60747-5-5 available with option 1
- BSI IEC 60950: IEC 60065

ORDER INFORMATION	
PART	REMARKS
IL201	CTR 75 to 150 %, DIP-6
IL202	CTR 125 to 250 %, DIP-6
IL203	CTR 225 to 450 %, DIP-6
IL203-X007	CTR 225 to 450 %, SMD-6 (option 7)
IL203-X009	CTR 225 to 450 %, SMD-6 (option 9)

#### Note

For additional information on the available options refer to option information.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
INPUT							
Peak reverse voltage		$V_R$	6.0	V			
Forward continuous current		I <sub>F</sub>	60	mA			
Power dissipation		P <sub>diss</sub>	100	mW			
Derate linearly from 25 °C			1.33	mW/°C			
OUTPUT							
Collector emitter breakdown voltage		BV <sub>CEO</sub>	70	V			
Emitter collector breakdown voltage		BV <sub>ECO</sub>	7.0	V			
Collector base breakdown voltage		BV <sub>CBO</sub>	70	V			
Power dissipation		P <sub>diss</sub>	200	mW			
Derate linearly from 25 °C			2.6	mW/°C			



### Optocoupler, Phototransistor Output, Vishay Semiconductors Low Input Current, Low Input Current, with Base Connection

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
COUPLER						
Isolation test voltage	t = 1.0 s	V <sub>ISO</sub>	5300	V <sub>RMS</sub>		
Total package dissipation (LED and detector)		P <sub>tot</sub>	250	mW		
Derate linearly from 25 °C			3.3	mW/°C		
Creepage distance			≥ 7.0	mm		
Clearance distance			≥ 7.0	mm		
Storage temperature		T <sub>stg</sub>	- 55 to + 150	°C		
Operating temperature		T <sub>amb</sub>	- 55 to + 100	°C		
Lead soldering time	≤ 260 °C		10	s		

### Note

T<sub>amb</sub> = 25 °C, unless otherwise specified.

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

ELECTRICAL CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT				•	•	•
Forward voltage	I <sub>F</sub> = 20 mA	V <sub>F</sub>		1.2	1.5	V
Forward voltage	I <sub>F</sub> = 1.0 mA	V <sub>F</sub>		1.0	1.2	V
Breakdown voltage	I <sub>R</sub> = 10 μA	V <sub>F</sub>	6.0	20		V
Reverse current	V <sub>R</sub> = 6.0 V	I <sub>R</sub>		0.1	10	μΑ
OUTPUT						
DC forward current gain	$V_{CE} = 5.0 \text{ V}, I_{C} = 100 \mu\text{A}$	h <sub>FE</sub>	100	200		
Collector emitter breakdown voltage	I <sub>C</sub> = 100 μA	BV <sub>CEO</sub>	70			V
Emitter collector breakdown voltage	I <sub>E</sub> = 100 μA	BV <sub>ECO</sub>	7.0	10		V
Collector base breakdown voltage	I <sub>C</sub> = 10 μA	BV <sub>CBO</sub>	70	90		V
Leakage current collector emitter	V <sub>CE</sub> = 10 V, T <sub>A</sub> = 25 °C	I <sub>CEO</sub>		5.0	50	nA

#### Note

 $T_{amb} = 25$  °C, unless otherwise specified. Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Current transfer ratio (collector to base)	$I_F = 10 \text{ mA}, V_{CB} = 10 \text{ V}$		CTR <sub>CB</sub>	15			%
Current transfer fatio (collector to base)	$I_F = 10 \text{ mA}, I_C = 2.0 \text{ mA}$		CTR <sub>CB</sub>			40	%
DC current transfer ratio	I <sub>F</sub> = 10 mA, V <sub>CB</sub> = 10 V	IL201	CTR <sub>DC</sub>	75	100	150	%
		IL202	CTR <sub>DC</sub>	125	200	250	%
		IL203	CTR <sub>DC</sub>	225	300	450	%
DC current transfer fatto		IL201	CTR <sub>DC</sub>	10			%
	$I_F = 1.0 \text{ mA}, V_{CE} = 10 \text{ V}$	IL202	CTR <sub>DC</sub>	30			%
		IL203	CTR <sub>DC</sub>	50			%

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### **TYPICAL CHARACTERISTICS**

T<sub>amb</sub> = 25 °C, unless otherwise specified

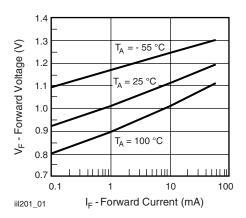


Fig. 1 - Forward Voltage vs. Forward Current

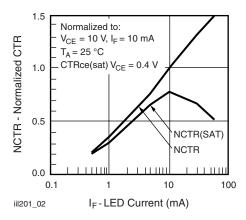


Fig. 2 - Normalized Non-Saturated and Saturated CTR vs. LED Current

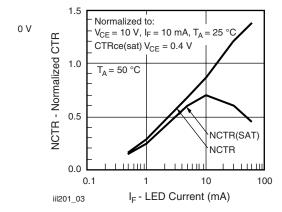


Fig. 3 - Normalized Non-Saturated and Saturated CTR vs. LED Current

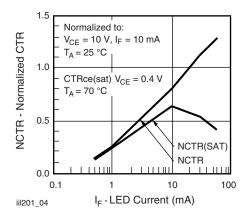


Fig. 4 - Normalized Non-Saturated and Saturated CTR vs. LED Current

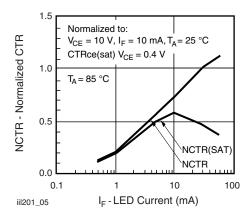


Fig. 5 - Normalized Non-Saturated and Saturated CTR vs. LED Current

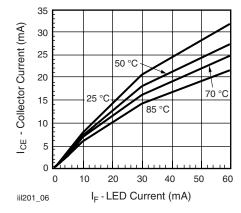


Fig. 6 - Collector Emitter Current vs. Temperature and LED Current



### Optocoupler, Phototransistor Output, Vishay Semiconductors Low Input Current, Low Input Current, with Base Connection

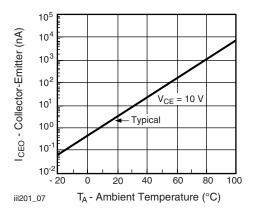


Fig. 7 - Collector Emitter Leakage Current vs.Temperature

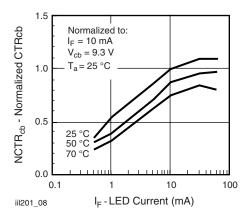


Fig. 8 - Normalized  $\mathsf{CTR}_\mathsf{cb}$  vs. LED Current and Temperature

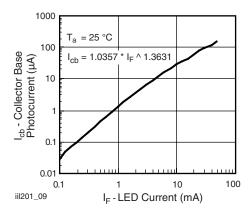


Fig. 9 - Collector Base Photocurrent vs. LED Current

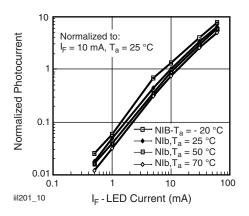


Fig. 10 - Normalized Photocurrent vs. IF and Temperature

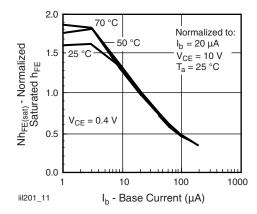


Fig. 11 - Normalized Saturated  $h_{\text{FE}}$  vs. Base Current and Temperature

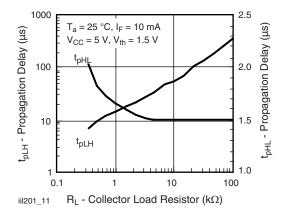
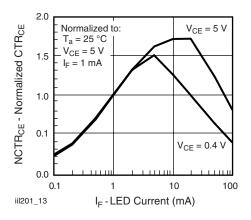


Fig. 12 - Propagation Delay vs. Collector Load Resistor

# Vishay Semiconductors

Optocoupler, Phototransistor Output, Low Input Current, Low Input Current, with Base Connection



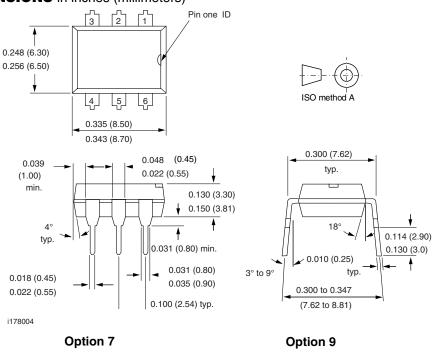


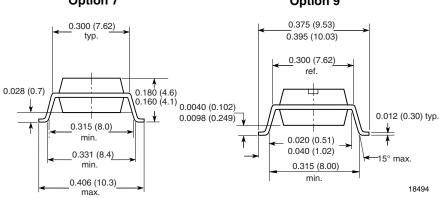
1.2 Normalized to:  $I_b = 20 \, \mu A$   $V_{CE} = 10 \, V - I_a = 25 \, ^{\circ}C$  0.8 0.4 1 10 100 1000  $I_b = 20 \, \mu A$   $I_b = 20 \,$ 

Fig. 13 - Normalized Non-Saturated and Saturated CTR<sub>CE</sub> vs. LED Current

Fig. 14 - Normalized Non-Saturated  $h_{\text{FE}}$  vs. Base Current and Temperature

### **PACKAGE DIMENSIONS** in inches (millimeters)







Optocoupler, Phototransistor Output, Low Input Current, Low Input Current, Vishay Semiconductors

### with Base Connection

### **OZONE DEPLETING SUBSTANCES POLICY STATEMENT**

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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Vishay

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